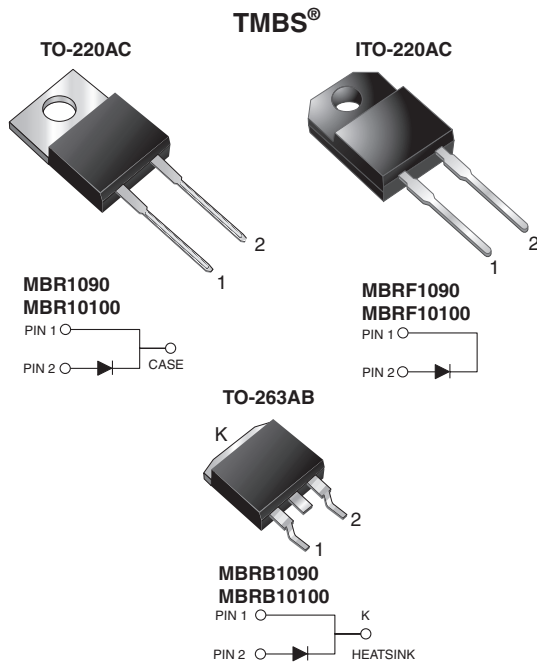


## High-Voltage Schottky Rectifier



### FEATURES

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AC and ITO-220AC package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



RoHS  
COMPLIANT

### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

### MECHANICAL DATA

**Case:** TO-220AC, ITO-220AC, TO-263AB

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for commercial grade, meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	10 A
$V_{RRM}$	90 V, 100 V
$I_{FSM}$	150 A
$V_F$	0.65 V
$T_J \text{ max.}$	150 °C

### MAXIMUM RATINGS ( $T_C = 25 \text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	MBR1090	MBR10100	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	90	100	V
Working peak reverse voltage	$V_{RWM}$	90	100	V
Maximum DC blocking voltage	$V_{DC}$	90	100	V
Maximum average forward rectified current at $T_C = 133 \text{ °C}$	$I_{F(AV)}$	10		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	150		A
Peak repetitive reverse current at $t_p = 2 \text{ }\mu\text{s}$ , 1 kHz	$I_{RRM}$	0.5		A
Voltage rate of change (rated $V_R$ )	$dV/dt$	10 000		V/ $\mu\text{s}$
Operating junction and storage temperature range	$T_J, T_{STG}$	- 65 to + 150		°C
Isolation voltage (ITO-220AC only) From terminal to heatsink $t = 1 \text{ min}$	$V_{AC}$	1500		V

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage <sup>(1)</sup>	$I_F = 10\text{ A}$	$T_C = 25\text{ }^\circ\text{C}$	$V_F$	0.80	V
	$I_F = 10\text{ A}$	$T_C = 125\text{ }^\circ\text{C}$		0.65	
	$I_F = 20\text{ A}$	$T_C = 125\text{ }^\circ\text{C}$		0.75	
Maximum reverse current at working peak reverse voltage <sup>(2)</sup>		$T_J = 25\text{ }^\circ\text{C}$ $T_J = 100\text{ }^\circ\text{C}$	$I_R$	100 6.0	$\mu\text{A}$ mA

**Notes:**

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq 40\text{ ms}$

<b>THERMAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance	$R_{\theta JA}$ $R_{\theta JC}$	60 2.0	- 3.5	60 2.0	$^\circ\text{C/W}$

<b>ORDERING INFORMATION</b> (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AC	MBR10100-E3/4W	1.845	4W	50/tube	Tube
ITO-220AC	MBRF10100-E3/4W	1.661	4W	50/tube	Tube
TO-263AB	MBRB10100-E3/4W	1.384	4W	50/tube	Tube
TO-263AB	MBRB10100-E3/8W	1.384	8W	800/reel	Tape and reel

**RATINGS AND CHARACTERISTICS CURVES**

( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

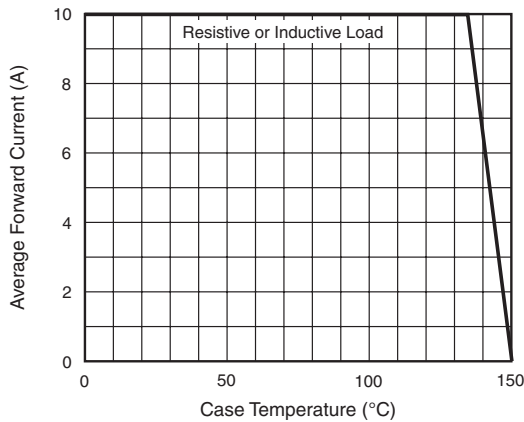


Figure 1. Forward Current Derating Curve

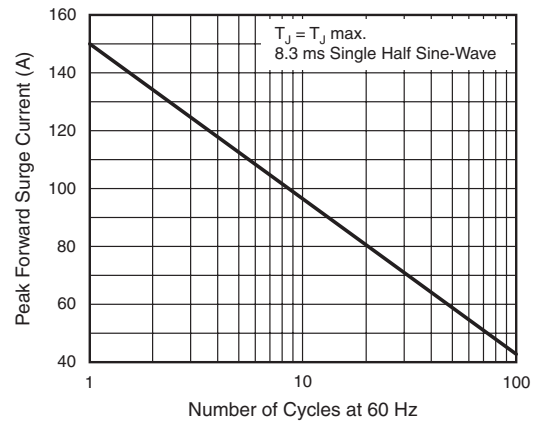


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



New Product

# MBR(F,B)1090 & MBR(F,B)10100

Vishay General Semiconductor

## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

